Vishay Semiconductors



Schottky Rectifier, 2 A



Cathode	Anode
0	O

SMA

PRODUCT SUMMARY				
Package	SMA			
I _{F(AV)}	2 A			
V _R	40 V			
V _F at I _F	0.63 V			
I _{RM}	26 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	3.0 mJ			

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
 COMPLIANT
 COMPLIANT
- Halogen-free according to IEC 61249-2-21
 HALOGEN
 Gefinition
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-20MQ040-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	2	А		
V _{RRM}		40	V		
I _{FSM}	t _p = 5 μs sine	120	А		
V _F	2 A _{pk} , T _J = 125 °C	0.63	V		
TJ	Range	- 55 to 150	۵°		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-20MQ040-M3	UNITS		
Maximum DC reverse voltage	V _R	40	V		
Maximum working peak reverse voltage	V _{RWM}	40	v		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDIT	TIONS	VALUES	UNITS
Maximum average forward current		50 % duty cycle at T_{C} = 110 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		2.1	
See fig. 4	IF(AV)	50 % duty cycle at T_{C} = 112 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		2	A
Maximum peak one cycle non-repetitive surge current I _{FSM} - See fig. 6		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	А
		10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	30	~
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 6 mH		3	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 1.0		А	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		2 A		0.69	V
		1.5 A	T _J = 25 °C	0.62	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	1 A		0.54	
See fig. 1	VFM (1)	2 A		0.63	
		1.5 A	T _J = 125 °C	0.56	
		1 A		0.49	
Maximum reverse leakage current		T _J = 25 °C	V Deted V	0.5	mA
See fig. 2	I _{RM}	$V_{\rm R}$ = Rated $V_{\rm R}$	$v_{\rm R}$ = Rated $v_{\rm R}$	26	
Threshold voltage	V _{F(TO)}	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad$		0.36	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}$, $T_J = 25 \text{ °C}$, test signal = 1 MHz		38	pF
Typical series inductance	Ls	Measured lead to lead 5 mm from package body 2.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µ		V/µs	

Note

 $^{(1)}$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approvimeto usisht			0.07	g
Approximate weight			0.002	oz.
Marking device		Case style SMA (similar D-64)	2	F

Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$



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30 35 40

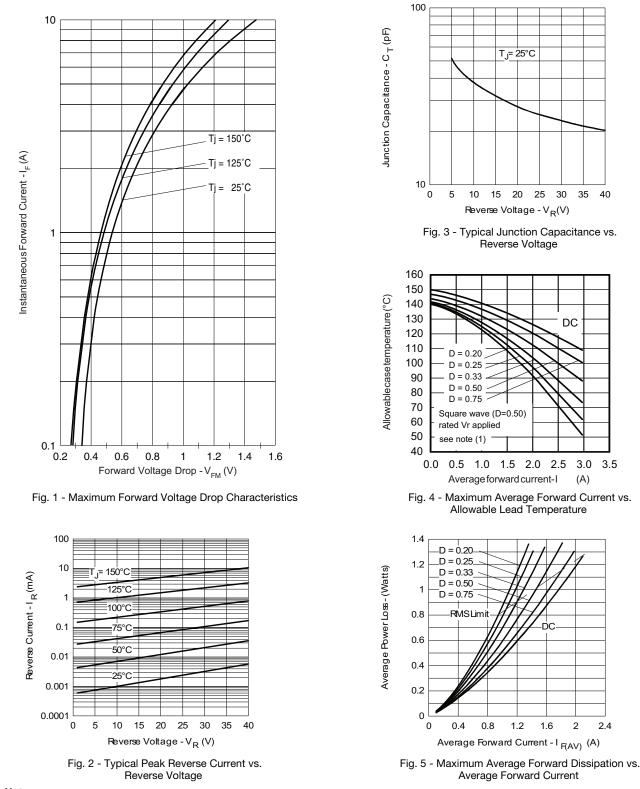
DC

3.0 3.5

(A)

2

2.4



Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

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Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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VS-20MQ040-M3

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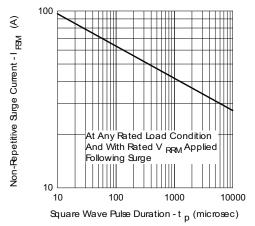
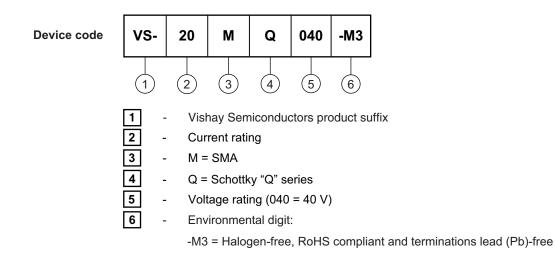


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-20MQ040-M3/5AT	5AT	7500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95400			
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		



Outline Dimensions

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SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





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